

<ul> <li>View Online at https://aerobasegroup.com/nsn/5961-00-892-9959</li> <li>Inclosure Material: Metal Overall Length: <ul> <li>0.180 inches</li> <li>Terminal Length:</li> <li>1.500 inches</li> </ul> </li> <li>Overall Diameter: <ul> <li>0.370 inches</li> </ul> </li> <li>Component Name And Quantity:</li> <li>2 transistor</li> <li>Mounting Method:</li> <li>Terminal</li> <li>Circle Diameter:</li> <li>0.200 inches</li> </ul> <li>Features Provided: <ul> <li>Hermetically sealed case</li> <li>Semiconductor Material:</li> <li>Silicon all transistor</li> <li>Voltage Rating In Volts Per Characteristic:</li> <li>60.00 milliamperes source cutoff current all transistor</li> <li>Power Rating Per Characteristic:</li> <li>2.0 milliwatts small-signal input power, common-collector absolute all transistor</li> </ul></li>	
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2.0 milliwatts small-signal input power, common-collector absolute all transistor	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Special Features:	
All transistor junction pattern arrangement: npn	
Terminal Type And Quantity:	
6 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	